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PTO Form 1449

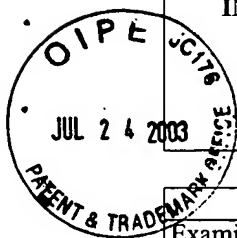
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Applicant
Hiroyuki Okuyama et al.

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Group
2822



U.S. PATENT DOCUMENTS

Examiner's Initials	Document Number	Publication Date	Inventor	Class	Subclass	Filing Date If Appropriate
MP	6,348,096	02/19/02	Kunakawa et al.	_____	_____	_____
MP	2002/0066403 A1	06/06/02	Sunakawa et al.	_____	_____	_____
MP	6,555,845 B2	04/29/03	Sunakawa et al.	_____	_____	_____

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FOREIGN PATENT DOCUMENTS

Examiner's Initials	Document Number	Publication Date	Country	Class	Subclass	Translation	
						Yes	No
MP	9-92881	04/04/1997	Japan	_____	_____	_____	✓
MP	9-162444	06/20/1997	Japan	_____	_____	_____	✓

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

Examiner's Initials	
MP	Journal of Crystal Growth 189/190 (1998), "Spatial Control Of InGaN Luminescence By MOCVD Selective Epitaxy", D. Kapolnek, S. Keller, R.D. Underwood, S.P. DenBaars, U.K. Mishra, pp. 83-86

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